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TOCONS



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GENERAL INFORMATION ABOUT THE SGLUX TOCONS

What is a TOCON?

A TOCON is a UV photodetector that contains a SiC or a GaP detector chip and an amplifier circuit that outputs a voltage of o to 5 V. This output voltage is linear in proportion to the UV radiation intensity reaching the SiC chip. Compared with a bare UV photodiode the TOCON's big advantage is the amplifier's position inside the TO5 metal housing and its close proximity to the detector. This construction protects the usually very low current levels generated by the detector chip from electromagnetic interference and also from moisture and pollution induced disturbances. A point to be considered of the TOCON is the lower dynamic range (approx. 3 orders of magnitude) compared with a SiC UV photodiode (10 orders of magnitude). To overdome this disadvantage we offer each TOCON type in many different amplification levels to avoid saturation and too low voltage output levels for nearly all applications. Please consult the selection guide on page 2 for assistance selecting the best suited TOCON.

About the material SiC

Most of the TOCONs are based on Silicon Carbide (SiC). Applications that require UV photodiodes differ widely in both required detector properties as well as spectral and absolute sensitivity. In the field of flame detection very low radiation intensity must be reliably detected. The monitoring of UV purification lamps needs UV photodiodes without degradation for many years under high UV flux. Monitoring very powerful UV radiation emitted by UV curing lamps or LED arrays require UV photodiodes that endure extreme UV radiation. Monitoring the sun's UV, in particular the erythemal intensity of the sunlight requires photodiodes with a near-perfect visible blindness and carefully tailored spectral response in the UV region. Customers that apply Silicon Carbide UV photodiodes do the best selection within all fields of applicaton. They profit from very low dark current, near perfect visible blindness and "bullet proof" radiation hardness.

Our own SiC wafer production since 2009

Since 2009 sglux produces SiC photodiodes, SiC spectrometer arrays and SiC 4-quadrant chips. The sglux R&D team has almost 20 years of experience in producing UV sensitive semiconductor chips. This skill powered the SiC R&D work focusing on extreme radiation hardness. The German PTB in 2011 measured that the radiation hardness of the sglux SiC UV chips has improved by factor of two compared to UV sensing chips produced by Cree, Inc. until 2007. Furthermore the visible blindness of the sglux chips could be improved by five orders of magnitude compared with Cree SiC chips now totaling to more than ten orders of magnitude of visible blindness. Please also refer to our list of publications (p. 10) of this catalog.

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SELECTION GUIDE

Nomenclature

TOCON	ABC, A, B, C, E, blue or GaP	1 10
	Spectral response	Irradiance limits (V _{supply} =5V, $\lambda = \lambda_{peak}$)
	ABC = broadband $\lambda_{mm} = 290 \text{ nm} \lambda_{mm} = 227 \text{ nm} \dots 360 \text{ nm}$	1 = 1.8 pW/cm ² 1.8 nW/ cm ²
		2 = 18 pW/cm ² 180 nW/ cm ²
	$\lambda_{max} = 331 \text{ nm} \ \lambda_{s10\%} = 309 \text{ nm} \dots 367 \text{ nm}$	3 = 180 pW/cm ² 1.8 μW/ cm ²
	B = UVB $λ_{max}$ = 280 nm $λ_{s10\%}$ = 243 nm 303 nm	$4 = 1.8 \text{ nW/cm}^2 \dots 18 \mu \text{W/ cm}^2$
		5 = 18 nW/cm ² 18ο μW/ cm ²
	C = UVC $\lambda_{max} = 275 \text{ nm } \lambda_{s10\%} = 225 \text{ nm } \dots 287 \text{ nm}$	6 = 180 nW/cm ² 1.8 mW/ cm ²
	Blue = blue light	7 = 1.8 μW/cm ² 18 mW/ cm ²
	$\lambda_{max} = 445 \text{ nm } \lambda_{s10\%} = 390 \text{ nm } \dots 515 \text{ nm}$	$8 = 18 \mu\text{W/cm}^2 \dots 180 \text{mW/cm}^2$
	GaP = UV + VIS	9 = 180 µW/cm ² 1.8 W/ cm ²
	M _{max} 445 min 70 _{510%} - 240 min 500 min	10 = 1.8 mW/cm ² 18 W/ cm ²
	E = UV-INDEX spectral response according to ISO 17166	2 = UVI 0 30

Some examples for different applications:

for flame detection
for water purification control
for UV-Index measurements



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Selection of spectral response

The TOCONs are available with six different spectral responses, Broadband UV "ABC", UVA "A", UVB "B", UVC "C" and Erythema Curve "E" (also useful for other selective UVB/UVC measurements) and blue light "BLUE" and "GaP" for near UV (UVA+blue+VIS). The below table shows the spectral response of the different TOCONs. For detailed specification please refer to our model overview (page 6) and the datasheet.





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Selection of sensitivity range

The selection of the sensitivity range must be thorough. If the TOCON is too sensitive it will saturate below the upper limit of the radiation range to be measured. Conversely, a TOCON that is too insensitive gives no or a too low voltage output. Thus, for dynamic range selection, please estimate, it is best to calculate what is the max. radiation your TOCON must measure without getting saturated (the sensor will not be damaged if saturated). If not possible, we recommend to procure two samples with different sensitivities and have an experiment. The related min. radiation is lower by approx. factor 5000 – if the TOCON is powered with 5 V. It is possible to power the TOCON with lower voltages down to 2.5 V. However, this will reduce the dynamic range by factor 5 V/V_{supply}. The graph below shows the sglux TOCONs offered spread out over a radiant intensity range of 13 orders of magnitude. The dynamic range is determined by the numeric suffix from "1" = very sensitive for very low UV radiation (e.g. a flame) to "10" = very unsensitive for very strong radiation (e.g curing source). For detailed specification please refer to our model overview (page 6) and the datasheet.







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HOW TO USE A TOCON?

The o to 5 V output voltage can be directly connected to a voltmeter or a controller. The TOCON is to be supplied with a voltage of $V_{supply} = 2.5 - 5 V_{DC}$ between pin V_s and pin *GND*. The voltage output signal is measured between pin *OUT* und pin *GND*.



PRODUCT DETAILS OF ALL TOCONS General specifications

	SYMBOL	VALUE	UNIT
Maximum Ratings			
Operating Temperature Range	T _{opt}	-25 +85	°C
Storage Temperature Range	T _{stor}	-40 + 100	°C
Solding Temperature (3s)	T_{sold}	300	°C
			• • • • • • • • • • • • • • • • • • • •
General Characteristics			
Supply voltage	V _{supply}	-2.5 +5.0	V
Saturation voltage	V _{sat}	V _{supply} -5%	V
Dark offset voltage	V _{offset}	50	μV
Temperature coefficient	Тс	<-0.3	%/K
Current consumption	I	150	μA
Bandwith (-3 dB)	Q	15	Hz
Risetime (10–90%)	t _{rise}	0.058 – 0.182	S
(other risetimes on request)			

Spectral Characteristics (T = 25°C, V_____ = +5V)

Typical respons. at peak wavelength	S _{max}	see next pages	nm
Wavelength of max. spectral responsivity	l _{max}	see next pages	nm
Responsivity range (S = $0.1 \times S_{max}$)	-	see next pages	nm
SiC Visible blindness (S _{max} / S _{>405nm})	VB	>10 ¹⁰ (SiC)	-

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sglux The UV Experts

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TOCON model overview

Model	Approx. min. irradiance (mW/cm ²)	Approx. max. irradiance (V _{supply} =5V) (mW/cm ²)	Applications

Broadband UV (SiC) Peak wavelength = 290 nm / sensivity range (S = $0.1^{+}S_{max}$) = 227 nm-360 nm

TOCON ABC 1	1.80 E–09	1.80 E–05	Very low UV radiation detection, flame detection
TOCON ABC 2	1.80 E–08	1.80 E–04	Low UV radiation detection, occupational safety
TOCON ABC 3	1.80 E–07	1.80 E–03	UV radiation detection, occupational safety
TOCON ABC 4	1.80 E–06	1.80 E-02	UV irradiation measurement
TOCON ABC 5	1.80 E-05	1.80 E-01	UV irradiation measurement
TOCON ABC 6	1.80 E–04	1.80 E + 00	Optimized for total sun UV measurements (not Erythema curve)
TOCON ABC ₇	1.80 E-03	1.80 E + 01	UV irradiation measurement, industrial standard UV radiation
TOCON ABC 8	1.80 E-02	1.80 E + 02	Curing lamp control
TOCON ABC 9	1.80 E–01	1.80E+03	Curing lamp control
TOCON ABC 10	1.80 E + 00	1.80 E + 04	UV hardening control and other very high radiation sources

UVA selective (SiC) Peak wavelength = 331 nm / sensivity range (S = $0.1^{+}S_{max}$) = 309 nm-367 nm

TOCON A 4	1.80 E–06	1.80 E-02	UVA radiation detection
TOCON A 5	1.80 E-05	1.80 E–01	UVA irradiation measurement
TOCON A 6	1.80 E-04	1.80 E + 00	UVA irradiation measurement
TOCON A7	1.80 E-03	1.80 E + 01	UVA irradiation measurement
TOCON A 8	1.80 E-02	1.80 E + 02	Measurement of high UVA irradiation, curing lamp control
TOCON A 9	1.80 E-01	1.80 E + 03	Measurement of very high UVA irradiation, curing lamp control

UVB + UVC selective (SiC) Peak wavelength = 280 nm / sensivity range (S = $0.1^{+}S_{max}$) = 243 nm-303 nm for LIVB + LIVC measurements and for Frythema Curve complies with LSO 17166 and DIN5050

for UVB + UVC me	asurements and for I	Erythema Curve, con	nplies with ISO 17166 and DIN5050	
	7.50 E-07	7.50 E-03	UVB irradiation measurement	

TOCON B 4	7.50 E-07	7.50 E-03	UVB irradiation measurement
TOCON B 5	7.50 E-06	7.50 E-02	UVB irradiation measurement
TOCON B6	7.50 E–05	7.50 E–01	UVB irradiation measurement
1 UVI input produces	electrical output		
TOCON E1	UVI 0.01	UVI 3	UV-Index measurements, if an attenuating diffusor is used
TOCON E 2	UVI 0.1	UVI 30	UV-Index measurements
TOCON_E_OEM	UVI 0.03	UVI 10	UV-Index measurements, designed to work with customers
			cosine correction dome



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TOCON model overview



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Model	Approx irradi (mW/	x. min. ance cm²)	Approx. max. irradiance (V _{supply} = 5V) (mW/cm ²)	Applications	
UVC selective (SiC) Pea	ak waveleng	gth = 275 nm / sensi	vity range (S = 0.1*S $_{max}$) = 225 nm–287 nm; complies with DVGW W294(3) and ÖNorm	
TOCON C 1	1.80 E	-08	1.80 E–04	UVA + UVB blind, for fire detection	
TOCON C 2	1.80 E-	-08	1.80 E–04	Low UVC radiation detection, occupational safety	
TOCON C3	1.80 E-	-07	1.80 E–03	UVC radiation detection, occupational safety	
TOCON C 4	1.80 E-	-06	1.80 E–02	UVC irradiation measurement	
TOCON C 5	1.80 E-	-05	1.80 E–01	Purification lamp control	
TOCON C 6	1.80 E-	-04	1.80 E + 00	Purification lamp control	
TOCON C ₇	1.80 E-	-03	1.80 E + 01	Purification lamp control	
TOCON C8	1.80 E-	-02	1.80 E + 02	Curing lamp control	
TOCON C9	1.80 E-	-01	1.80 E + 03	Curing lamp control	
••••••		• • • • • • • • • • • • • •	• • • • • • • • • • • • • • • • • • • •		
Blue Light (Gal	P) Peak w	vavelength	= 445 nm / sensivity	range (S = 0.1*S _{max}) = 390 nm–515 nm; complies with 2006/25/EC	
TOCON BLUE 4	9.00 E	-07	9.00 E-03	Measurement of very low blue light irradiation, occupational safety	
TOCON BLUE 5	9.00 E	-06	9.00 E-02	Measurement of low blue light irradiation, occupational safety	
TOCON BLUE 6	9.00 E	-05	9.00 E - 01	Measurement of blue light irradiation, occupational safety	
TOCON BLUE 7	9.00 E	-04	9.00 E + 00	Measurement of blue light irradiation, occupational safety	
TOCON BLUE 8	9.00 E	-03	9.00 E + 01	Measurement of high blue light irradiation, occupational safety	
TOCON BLUE 9	9.00 E	-02	9.00 E + 02	Measurement of very high blue light irradiation, occupational safety	
••••••		• • • • • • • • • • • • •	• • • • • • • • • • • • • • • • • • • •		
UV + VIS (GaP)	Peak wa	velength =	445 nm / sensivity r	ange (S = 0.1*S _{max}) = 240 nm–560 nm	
TOCON GaP 4	9.00 E	-07	9.00 E–03	Measurement of very low UV & VIS light irradiation, occupational safety	
TOCON GaP 5	9.00 E	-06	9.00 E-02	Measurement of low UV & VIS light irradiation, occupational safety	
TOCON GaP6	9.00 E	-05	9.00 E - 01	Measurement of blue UV & VIS light irradiation, occupational safety	
TOCON GaP7	9.00 E	-04	9.00 E + 00	Measurement of blue UV & VIS light irradiation, occupational safety	
TOCON GaP8	9.00 E	-03	9.00 E + 01	Measurement of high UV & VIS light irradiation, occupational safety	
TOCON GaP9	9.00 E	-02	9.00 E + 02	Measurement of very high UV $\&$ VIS light irradiation, occupational safety	
· · ·					
TOCON housing					
IUCON NOUSINg miniature stai easy to mount		ount and connect, ro	bust thread body, suitable for all TOCONs		
TOCON PTFE ho	using	miniature easy to mo	PTFE housing (M12x ount and connect, di	a) with TOCON installed and removable 4-pin connector with 2 m cable, rt repellent	
TOCON Water h	ousing	miniature connector	water pressure proc with 2 m cable,eas	of (10 bar) housing with G1/4" thread with TOCON installed and removable 5-pin ay to mount and connect, dirt repellent	
TOCON Starter Kit		Kit for initial testing setup, includes a TOCON socket, two banana plugs to connect with a voltmeter and a 9 V block battery			

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Drawings



TOCON in TO5 housing with filter, diffusor and / or attenuator



TOCON in TO5 housing with lens cap

Application note for TOCONs

The TOCONs need a supply voltage of $V_{supply} = 2.5$ to 5 VDC and can be directly connected to a controller or voltmeter. Please note that the theoretic maximum signal output is always a little less (approx. 5%) than the supply voltage. To learn more about perfect use of the TOCONs please refer to the TOCON FAQ list published at www.sglux.com. CAUTION! Wrong wiring leads to destruction of the device. For easy setup of the device please ask for a TOCON starter kit that contains a ready to use wired socket, a connector to a 9V battery, 2 banana plugs for Vout.



Accessories







- Small housing for the TOCON series
- Supply voltage 7 to 24 V
- Robust stainless steel M12x1 thread body
- Integrated sensor connector (Binder 4-Pin plug) with 2 m connector cable
- Easy to mount and connect

TOCON PTFE housing

- Small housing for the TOCON series
- Supply voltage 7 to 24 V
- Material teflon (PTFE) M12x1 thread body, dirt-repellent, water proof at wetside (IP68), wide cosine field of view
- Integrated sensor connector (Binder 4-Pin plug) with 2 m connector cable
- Easy to mount and connect, cleanable

TOCON water PTFE

- Miniature housing for the TOCON series
- Supply voltage 7 to 24 V
- G1/4" thread, material Teflon (PTFE)
- 10 bar water pressure proof
- Integrated sensor connector (Binder 5-Pin plug) with 2 m connector cable
- Easy to mount and connect



Plastic probes for TOCON series

- UV probes in small plastic housings with a TOCON inside
- Customized housings available
- Easy to mount and to connect
- Integrated sensor connector (Binder 4-Pin plug)
- Connector cable available



TOCON Starter kit

- Optional feature for all TOCON detectors
- kit for easy initial testing setup
- output voltage o to 5 V
- 9 V block battey included, easy connection via banana plug ground





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LIST OF PUBLICATIONS

P. Sperfeld¹, B. Barton¹, S. Pape¹, A. Towara¹, J. Eggers², G. Hopfenmueller³

¹Physikalisch-Technische Bundesanstalt Braunschweig und Berlin (PTB), Germany, ²DVGW-Technologiezentrum Wasser, Karlsruhe, Germany, ³sglux GmbH, Berlin, Germany

"SPECTRAL IRRADIANCE MEASUREMENT AND ACTINIC RADIOMETER CALIBRATION FOR UV WATER DISINFECTION" Metrologia, Issue 51 (2014), p. 282-288.

P. Sperfeld¹, B. Barton¹, S. Pape¹, A. Towara¹, J. Eggers², G. Hopfenmueller³

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"SPECTRAL IRRADIANCE MEASUREMENT AND ACTINIC RADIOMETER CALIBRATION FOR UV WATER DISINFECTION" Proceedings of NEWRAD 2014, edited by S. Park, P. Kaerhae and E. Ikonen. (Aalto University, Espoo, Finland 2014) *P. 128*.

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¹Physikalisch-Technische Bundesanstalt Braunschweig und Berlin (PTB), 4.1 Photometry and Applied Radiometry, Braunschweig, Germany, ²sglux GmbH, Berlin, Germany

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P. Sperfeld¹, B. Barton¹, S. Pape¹, G. Hopfenmueller²

¹Physikalisch-Technische Bundesanstalt Braunschweig und Berlin (PTB), 4.1 Photometry and Applied Radiometry, Braunschweig, Germany, ²sglux GmbH, Berlin, Germany

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G. Hopfenmueller¹, T.Weiss¹, B. Barton², P. Sperfeld², S. Nowy², S. Pape², D. Friedrich², S. Winter², A. Towara²,

A. Hoepe², S. Teichert²

¹sglux GmbH, Berlin, Germany, ²Physikalisch-Technische Bundesanstalt Braunschweig und Berlin (PTB), 4.1 Photometry and Applied Radiometry, Braunschweig, Germany

"PTB traceable calibrated reference UV radiometer for measurements at high irradiance medium pressure mercury discharge lamps"

EMEA Regional Conference, Karlsruhe, Germany (2013)

D. Prasai¹, W. John¹, L. Weixelbaum¹, O. Krueger¹ G. Wagner², P. Sperfeld³, S. Nowy³, D. Friedrich³, S. Winter³ and T. Weiss⁴

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4.1 Photometry and Applied Radiometry, Braunschweig, Germany, 4sglux GmbH, Berlin, Germany

"HIGHLY RELIABLE SILICON CARBIDE PHOTODIODES FOR VISIBLE-BLIND ULTRAVIOLET DETECTOR APPLICATIONS" J. Mater. Res., first view (2012)

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B. Barton¹, P. Sperfeld¹, S. Nowy¹, A. Towara¹, A. Hoepe¹, S. Teichert¹, G. Hopfenmueller², M. Baer³, and T. Kreuzberger³

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